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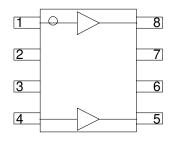
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SIRENZA MICRODEVICES Product Description

Sirenza Microdevice's CGA-3318 is a high performance Silicon Germanium HBT MMIC Amplifier. Designed with SiGe process technology for excellent linearity at an exceptional price. A Darlington configuration is utilized for broadband performance. The heterojunction increases breakdown voltage and minimizes leakage current between junctions. The CGA-3318 contains two amplifiers for use in wideband Push-Pull CATV amplifiers requiring excellent second order performance. The second and third order non-linearities are greatly improved in the push pull configuration.

Amplifier Configuration



ELECTRICAL SPECIFICATIONS

CGA-3318 CGA-3318Z

RoHS Compliant & Green Package

Dual CATV Broadband High Linearity SiGe HBT Amplifier



Product Features

- Available in Lead free, RoHS compliant, & Green packaging
- Excellent CSO/CTB/XMOD Performance at +34 dBmV Output Power per Tone
- Dual Devices in each SOIC-8 Package simplify Push-Pull configuration PC board layout
- 5 to 900 MHz operation

Applications

- CATV Head End Driver and Predriver Amplifier
- CATV Line Driver Amplifier

LLLCINICAL	SFLOILICATIONS	•••••				
Symbol	Parameter	Freq.(MHz)	Min.	Тур.	Max.	Units
G	Small Signal Gain	5 50 500 870	10.0	13.2 12.5 12.5 12.0		dB
O IP 2	Output Second Order Intercept Point Tone Spacing = 1 MHz, Pout per tone = +6 dBm	50 250 500	67.0	69.0 71.5 69.0		dBm
O IP 3	Output Third Order Intercept Point Tone Spacing = 1 MHz, Pout per tone = +6 dBm	50 500 870	36.0	36.5 38.0 38.0		dBm
P1dB	Output Power at 1dB Gain Compression	50 500 870	18.6	20.0 21.0 20.6		dBm
IRL	Input Return Loss	500 50-870	10	17.0		dB
ORL	Output Return Loss	500 50-870	10	12.0		dB
NF	Noise Figure Balun Insertion Loss Included	50 500 870		4.2 4.3 5.0	6.0	dB
CSO	Worst Case Over Band, 79 Ch., Flat, +34dBm\	/		70		dBc
СТВ	Worst Case Over Band, 79 Ch., Flat, +34dBm	/		68		dBc
XMOD	Worst Case Over Band, 79 Ch., Flat, +34dBm	/		63		dBc
V _D	Device Operating Voltage		3.9	4.1	4.3	V
I _D	Device Operating Current		135	150	165	m A
$R_{_{TH(J-L)}}$	Thermal Resistance (Junction to Lead)			50		°C/W

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Absolute Maximum Ratings

Parameter	Absolute Limit		
Max Device Current (I _D)	225 mA		
Max Device Voltage (V_D)	6 V		
Max. RF Input Power	+18 dBm		
Max. Junction Temp. (T_J)	+150°C		
Operating Temp. Range (T_L)	-40°C to +85°C		
Max. Storage Temp.	+150°C		

Operation of this device beyond any one of these limits may cause permanent damage. For reliable continuous operation, the device voltage and current must not exceed the maximum operating values specified in the table on page one.

Bias Conditions should also satisfy the following expression: $I_DV_D < (T_J - T_L) / R_{TH}, j-I T_L=T_{LEAD}$

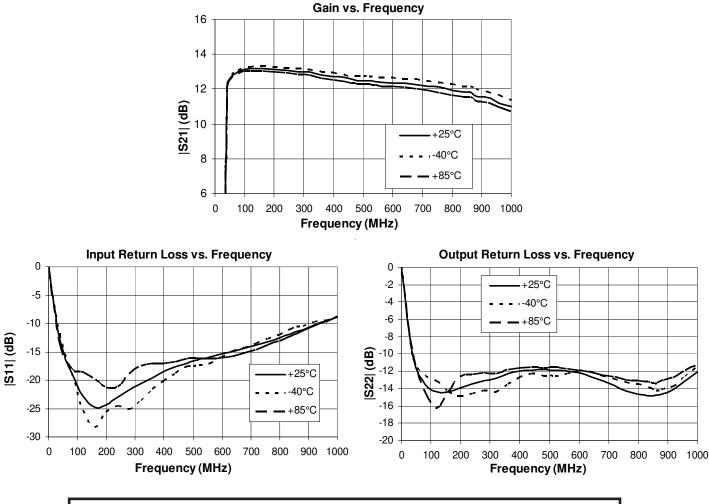
Reliability & Qualification Information				
Parameter	Rating			
ESD Rating - Human Body Model (HBM)	Class 1B			
Moisture Sensitivity Level	MSL 1			
This product qualification report can be downloaded at				
www.sirenza.com				



Caution: ESD sensitive

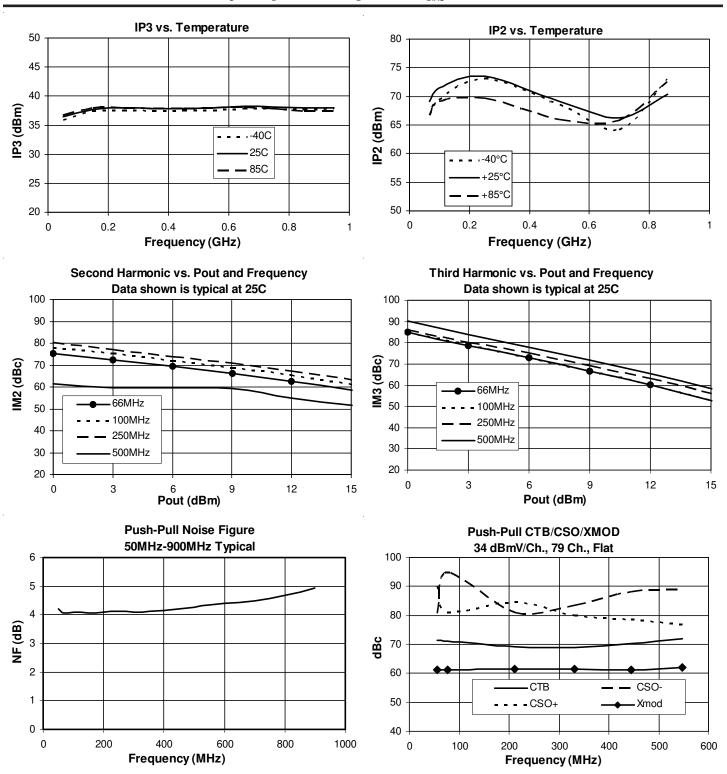
Appropriate precautions in handling, packaging and testing devices must be observed.

Typical RF Performance: $V_s=8V$, $I_p=150mA @ T_L=+25^{\circ}C$, $R_{_{BIAS}}=51$ Ohms, Push-Pull Configuration



75 Ohm Push Pull S-parameters are available for download at www.sirenza.com





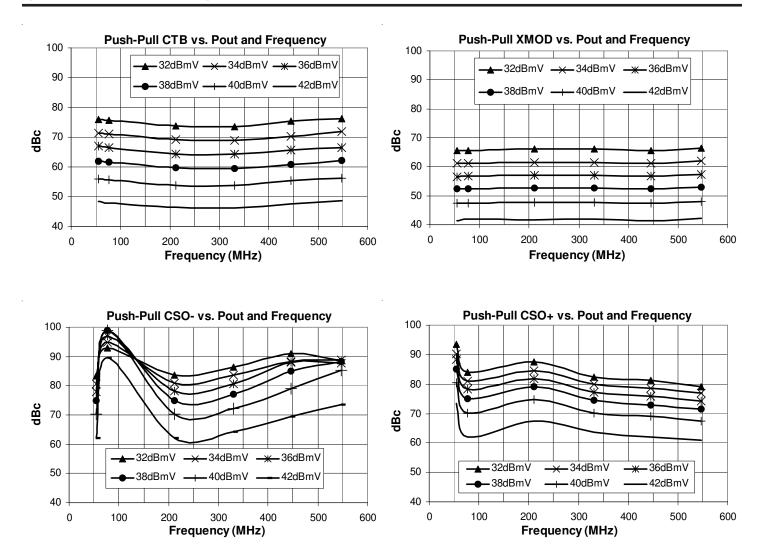
Typical RF Performance: V_s =8V, I_p =150mA @ T_L =+25°C, R_{BIAS} =51 Ohms, Push-Pull Configuration

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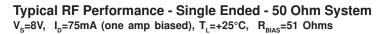
CSO/CTB/XMOD Performance:

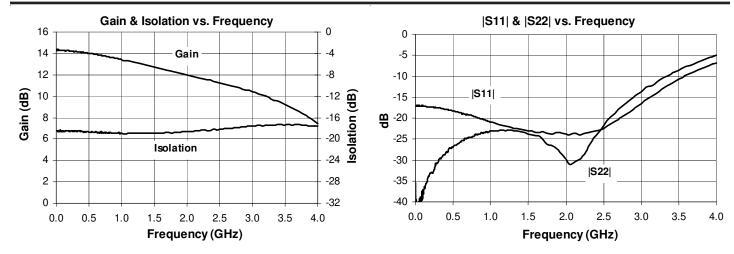
V_s=8V, I_p=150mA @ T_L=+25°C, R_{BIAS}=51 Ohms, Push-Pull Config, 79 Ch. Flat Analog, No Digital Channels.



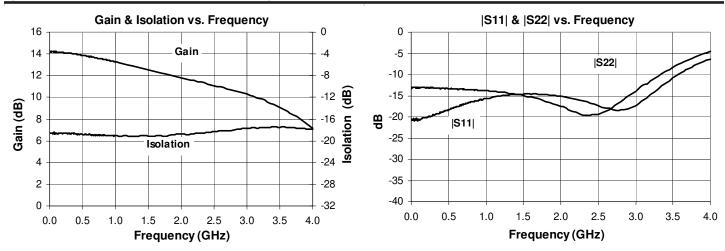
Note: CSO measurements > 85 dBc can be limited by system noise.







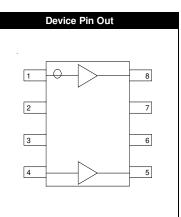
Typical RF Performance - Single Ended - 37.5 Ohm System V_s =8V, I_p =75mA (one amp biased), T_L =+25°C, R_{BIAS} =51 Ohms



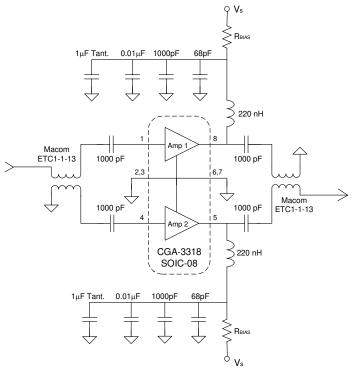
50 Ohm and 37.5 Ohm Single Ended S-parameter files are available for download at www.sirenza.com



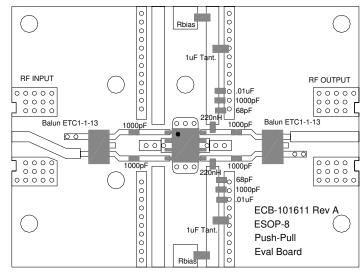
Pin #	Function	Description
1	RF IN Device 1	RF input pin. This pin requires the use of an external DC blocking capacitor as shown in the schematic.
2,3	Ground	Connection to ground. Use via holes for best performance to reduce lead inductance as close to ground leads as possible.
4	RF IN Device 2	Same as pin 1
5	RF OUT / Vcc Device 2	RF output and bias pin. Bias should be supplied to this pin through an external series resistor and RF choke inductor. Because DC biasing is present on this pin, a DC blocking capacitor should be used in most applications (see application schematic). The supply side of the bias network should be well bypassed.
6,7	Ground	Same as pins 2 and 3
8	RF OUT / Vcc Device 1	Same as pin 5
EPAD	Ground	Exposed area on the bottom side of the package must be soldered to the ground plane of the board for optimum thermal and RF performance. Several vias should be located under the EPAD as shown in the recommended land pattern on page 5.



50-870 MHz Application Schematic



50-870 MHz Evaluation Board Layout



Part Number Ordering Information

Part Number

CGA-3318

CGA-3318Z

Reel Size

7"

7"

Recommended Bias Resistor Values for ID= 150mA						
Supply Voltage (V _S)	8V	9V	12V	15V		
R _{BIAS}	51Ω	62Ω	100Ω	150Ω		
R _{BIAS} Power Rating	1/2W	1/2W	1W	1W		

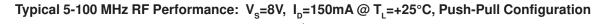
$$\mathsf{R}_{_{\text{BIAS}}} = \frac{2(\mathsf{V}_{_{\text{S}}} \text{-} \mathsf{V}_{_{\text{D}}})}{\mathsf{I}_{_{\text{D}}}}$$

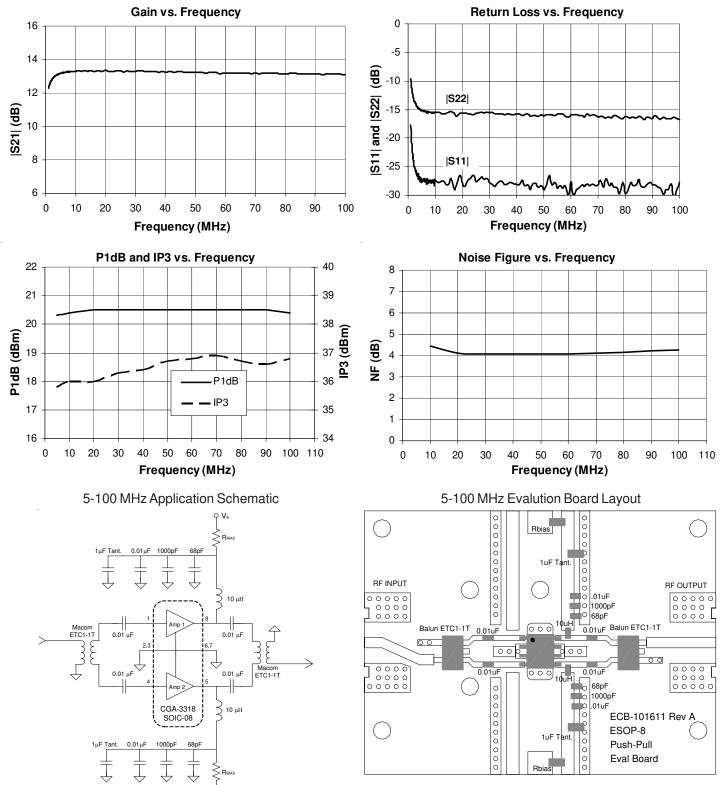
303 S. Technology Ct. Broomfield, CO 80021 **Devices / Reel**

500

500



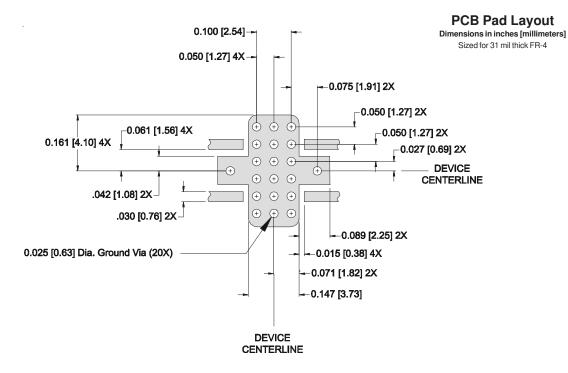




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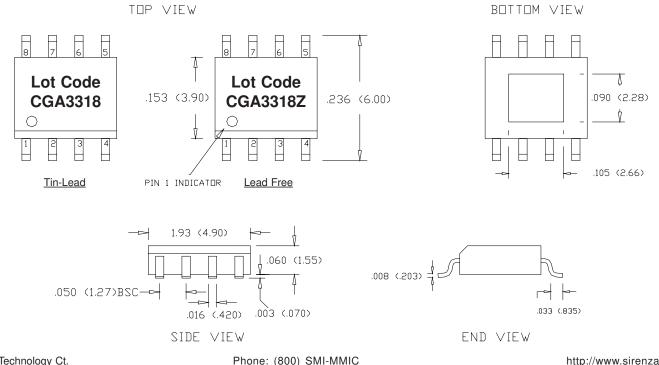
^d v₅





Nominal Package Dimensions & Package Marking Dimensions in inches [millimeters]

Refer to package drawing posted at www.sirenza.com for tolerances.



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